



AMP2010-1 SOLID STATE HIGH POWER AMPLIFIER

FEATURES

- Rack mount system
- Class AB linear GaN design
- Instantaneous wide bandwidth
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	2.0 - 6.0 GHz	
Power Output	50 Watt Min / 70 Watt Typ	CW
Power Gain	47 dB Min	
Power Gain Flatness	3.0 dB p-p Max	
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	37dBm/Tone, $\Delta = 1\text{MHz}$
Harmonics	-20 dBc Typ	At rated output power
Non-Harmonics Spurious	-60dBc Max	
Operating Voltage	100 - 240 VAC	Single phase
Power Consumption	500 Watt Max	At Rated Pout
Max Input Power Protection	+8 dBm	<10 Sec without damage
Load VSWR Protection	$\infty : 1$	<1 Minute
OPTIONAL: FWD Sample Port Coupling Factor	40 dB Nom	Front SMA female

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 88 x 562 mm	2U
Weight	10 kg.	
RF Connectors In/Out	Type-N Female	Front Panel Standard
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485, Optional GPIB Interface	Remote Bluetooth application

D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	Reserved	N/C
2	Reserved	N/C
3	CURRENT SENSOR	$I_D @ 50mV/100mA$ Typ
4	TEMP SENSOR	$V_T @ 10mV/^{\circ}C + 500mV$ Typ
5	SHUTDOWN	TTL - Standby Mode
6	VDD	Internal Power Supply Voltage
7	Reserved	N/C
8, 9	GND	Ground

OUTLINE DRAWING

